

L Number	Hits	Search Text	DB	Time stamp
1	613	438/22.ccls. or 438/26.ccls.	USPAT	2003/12/01 08:40
3	534	438/689.ccls. or 438/690.ccls.	USPAT	2003/12/01 08:41
5	1438	((438/691).CCLS. OR (438/692).CCLS.) not (438/689.ccls. or 438/690.ccls.)	USPAT	2003/12/01 08:44
-	530	134/1.3.ccls.	USPAT	2003/11/20 15:17
-	25	134/1.3.ccls. and (wip\$3)	USPAT	2003/11/20 15:18
-	15	((TFT or (thin adj film adj transistor\$2))) and (flattening adj treatment)	USPAT	2003/11/20 15:45
-	0	(flattening adj treatment) with anode	USPAT	2003/11/20 15:45
-	41	flattening with anode	USPAT	2003/11/20 15:45
-	8	((TFT or (thin adj film adj transistor\$2))) and (flattening with anode)	USPAT	2003/11/20 15:45
-	773	((TFT or (thin adj film adj transistor\$2))) and (polyvinyl adj alcohol)	USPAT	2003/11/20 16:13
-	208	TFT and resin and ((CMP or planariz\$6) with (pixel or anode or electrode))	USPAT	2003/11/20 16:14
-	152	(TFT and resin and ((CMP or planariz\$6) with (pixel or anode or electrode))) not (semiconductor and energy and laboratory).as.	USPAT	2003/11/20 16:16
-	0	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode or electrode))) not (semiconductor and energy and laboratory).as.) and (anode with CMP)	USPAT	2003/11/20 16:16
-	20	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode or electrode))) not (semiconductor and energy and laboratory).as.) and anode	USPAT	2003/11/20 16:19
-	112	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode or electrode))) not (semiconductor and energy and laboratory).as.) and (pixel adj electrode)	USPAT	2003/11/20 16:19
-	0	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode or electrode))) not (semiconductor and energy and laboratory).as.) and (pixel adj electrode)) and (planariz\$3 with anode)	USPAT	2003/11/20 16:19
-	44	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode or electrode))) not (semiconductor and energy and laboratory).as.) and (pixel adj electrode)) and (planariz\$3 with pixel)	USPAT	2003/11/20 16:22
-	1	((TFT and resin and ((CMP or planariz\$6) with (pixel or anode or electrode))) not (semiconductor and energy and laboratory).as.) and (pixel adj electrode)) and (planariz\$3 with pixel)) and (pixel with CMP)	USPAT	2003/11/20 16:24
-	8	TFT and display\$1 and ((anode or pixel) with (clean\$3 and flatten\$3))	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/11/20 16:29
-	73	((pixel adj electrode) or anode) with (CMP or (chemical adj mechanical adj polish\$3) or clean\$3 or wip\$3 or flat\$6)) and (TFT or (thin adj film adj transistor\$2))	USPAT	2003/12/01 08:39